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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Obsolete
Core Processor	MPC8xx
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	66MHz
Co-Processors/DSP	Communications; CPM
RAM Controllers	DRAM
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10Mbps (1), 10/100Mbps (1)
SATA	-
USB	-
Voltage - I/O	3.3V
Operating Temperature	-40°C ~ 100°C (TA)
Security Features	-
Package / Case	357-BBGA
Supplier Device Package	357-PBGA (25x25)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/kmpc859dslcvr66a

  - ATM port-to-port switching capability without the need for RAM-based microcode
  - Simultaneous MII (10/100Base-T) and UTOPIA (half-duplex) capability
  - Optional statistical cell counters per PHY
  - UTOPIA level 2 compliant interface with added FIFO buffering to reduce the total cell transmission time. (The earlier UTOPIA level 1 specification is also supported.)
    - Multi-PHY support on the MPC866, MPC859P, and MPC859T
    - Four PHY support on the MPC866/859
  - Parameter RAM for both SPI and I^2C can be relocated without RAM-based microcode
  - Supports full-duplex UTOPIA both master (ATM side) and slave (PHY side) operation using a 'split' bus
  - AAL2/VBR functionality is ROM-resident.
- Up to 32-bit data bus (dynamic bus sizing for 8, 16, and 32 bits)
- Thirty-two address lines
- Memory controller (eight banks)
  - Contains complete dynamic RAM (DRAM) controller
  - Each bank can be a chip select or $\overline{\text{RAS}}$ to support a DRAM bank
  - Up to 30 wait states programmable per memory bank
  - Glueless interface to page mode/EDO/SDRAM, SRAM, EPROMs, flash EPROMs, and other memory devices.
  - DRAM controller programmable to support most size and speed memory interfaces
  - Four $\overline{\text{CAS}}$ lines, four $\overline{\text{WE}}$ lines, and one $\overline{\text{OE}}$ line
  - Boot chip-select available at reset (options for 8-, 16-, or 32-bit memory)
  - Variable block sizes (32 Kbytes–256 Mbytes)
  - Selectable write protection
  - On-chip bus arbitration logic
- General-purpose timers
  - Four 16-bit timers cascadable to be two 32-bit timers
  - Gate mode can enable/disable counting
  - Interrupt can be masked on reference match and event capture
- Fast Ethernet controller (FEC)
  - Simultaneous MII (10/100Base-T) and UTOPIA operation when using the UTOPIA multiplexed bus
- System integration unit (SIU)
  - Bus monitor
  - Software watchdog
  - Periodic interrupt timer (PIT)
  - Low-power stop mode
  - Clock synthesizer
  - Decrementer and time base from the PowerPC architecture
  - Reset controller
  - IEEE 1149.1 test access port (JTAG)

- One serial peripheral interface (SPI)
  - Supports master and slave modes
  - Supports multiple-master operation on the same bus
- One inter-integrated circuit (I^2C) port
  - Supports master and slave modes
  - Multiple-master environment support
- Time slot assigner (TSA) (MPC859DSL does not have TSA.)
  - Allows SCCs and SMCs to run in multiplexed and/or non-multiplexed operation
  - Supports T1, CEPT, PCM highway, ISDN basic rate, ISDN primary rate, user-defined
  - 1- or 8-bit resolution
  - Allows independent transmit and receive routing, frame synchronization, and clocking
  - Allows dynamic changes
  - On MPC866P and MPC866T, can be internally connected to six serial channels (four SCCs and two SMCs); on MPC859P and MPC859T, can be connected to three serial channels (one SCC and two SMCs).
- Parallel interface port (PIP)
  - Centronics interface support
  - Supports fast connection between compatible ports on MPC866/859 or MC68360
- PCMCIA interface
  - Master (socket) interface, compliant with PCI Local Bus Specification (Rev 2.1)
  - Supports one or two PCMCIA sockets whether ESAR functionality is enabled
  - Eight memory or I/O windows supported
- Debug interface
  - Eight comparators: four operate on instruction address, two operate on data address, and two operate on data.
  - Supports conditions: = ≠ < >
  - Each watchpoint can generate a breakpoint internally
- Normal high and normal low power modes to conserve power
- 1.8 V core and 3.3 V I/O operation with 5-V TTL compatibility; refer to Table 6 for a listing of the 5-V tolerant pins.
- 357-pin plastic ball grid array (PBGA) package
- Operation up to 133 MHz

5 Power Dissipation

Table 5 shows power dissipation information. The modes are 1:1, where CPU and bus speeds are equal, and 2:1 mode, where CPU frequency is twice the bus speed.

Table 5. Power Dissipation (P_D)

Die Revision	Bus Mode	CPU Frequency	Typical [1]	Maximum [2]	Unit
0	1:1	50 MHz	110	140	mW
		66 MHz	150	180	mW
	2:1	66 MHz	140	160	mW
		80 MHz	170	200	mW
		100 MHz	210	250	mW
		133 MHz	260	320	mW

1 Typical power dissipation at VDDL and VDDSYN is at 1.8 V. and VDDH is at 3.3 V.

2 Maximum power dissipation at VDDL and VDDSYN is at 1.9 V, and VDDH is at 3.465 V.

NOTE

Values in Table 5 represent VDDL based power dissipation and do not include I/O power dissipation over VDDH. I/O power dissipation varies widely by application due to buffer current, depending on external circuitry. The VDDSYN power dissipation is negligible.

6 DC Characteristics

Table 6 shows the DC electrical characteristics for the MPC866/859.

Table 6. DC Electrical Specifications

Characteristic	Symbol	Min	Max	Unit
Operating voltage	VDDL (core)	1.7	1.9	V
	VDDH (I/O)	3.135	3.465	V
	VDDSYN [1]	1.7	1.9	V
	Difference between VDDL to VDDSYN	—	100	mV
Input high voltage (all inputs except EXTAL and EXTCLK) [2]	VIH	2.0	3.465	V

Table 6. DC Electrical Specifications (continued)

Characteristic	Symbol	Min	Max	Unit
Input low voltage	VIL	GND	0.8	V
EXTAL, EXTCLK input high voltage	VIHC	0.7*(VDDH)	VDDH	V
Input leakage current, Vin = 5.5V (except TMS, TRST, DSCK and DSDI pins) for 5 Volts Tolerant Pins [2]	I_{in}	—	100	µA
Input leakage current, Vin = VDDH (except TMS, TRST, DSCK, and DSDI)	I_{In}	—	10	µA
Input leakage current, Vin = 0 V (except TMS, TRST, DSCK and DSDI pins)	I_{In}	—	10	µA
Input capacitance [3]	C_{in}	—	20	pF
Output high voltage, IOH = – 2.0 mA, except XTAL, and Open drain pins	VOH	2.4	—	V
Output low voltage • IOL = 2.0 mA (CLKOUT) • IOL = 3.2 mA [4] • IOL = 5.3 mA [5] • IOL = 7.0 mA (TXD1/PA14, TXD2/PA12) • IOL = 8.9 mA (TS, TA, TEA, BI, BB, HRESET, SRESET)	VOL	—	0.5	V

1 The difference between VDDL and VDDSYN can not be more than 100 m V.

2 The signals PA[0:15], PB[14:31], PC[4:15], PD[3:15], TDI, TDO, TCK, TRST_B, TMS, MII_TXEN, MII_MDIO are 5 V tolerant.

3 Input capacitance is periodically sampled.

4 A(0:31), TSIZ0/REG, TSIZ1, D(0:31), DP(0:3)/IRQ(3:6), RD/WR, BURST, RSV/IRQ2, IP_B(0:1)/IWP(0:1)/VFLS(0:1), IP_B2/IOIS16_B/AT2, IP_B3/IWP2/VF2, IP_B4/LWP0/VF0, IP_B5/LWP1/VF1, IP_B6/DSDI/AT0, IP_B7/PTR/AT3, RXD1 /PA15, RXD2/PA13, L1TXDB/PA11, L1RXDB/PA10, L1TXDA/PA9, L1RXDA/PA8, TIN1/L1RCLKA/BRGO1/CLK1/PA7, BRGCLK1/TOUT1/CLK2/PA6, TIN2/L1TCLKA/BRGO2/CLK3/PA5, TOUT2/CLK4/PA4, TIN3/BRGO3/CLK5/PA3, BRGCLK2/L1RCLKB/TOUT3/CLK6/PA2, TIN4/BRGO4/CLK7/PA1, L1TCLKB/TOUT4/CLK8/PA0, REJCT1/SPISEL/PB31, SPICLK/PB30, SPIMOSI/PB29, BRGO4/SPIMISO/PB28, BRGO1/I2CSDA/PB27, BRGO2/I2CSCL/PB26, SMTXD1/PB25, SMRXD1/PB24, SMSYN1/SDACK1/PB23, SMSYN2/SDACK2/PB22, SMTXD2/L1CLKOB/PB21, SMRXD2/L1CLKOA/PB20, L1ST1/RTS1/PB19, L1ST2/RTS2/PB18, L1ST3/L1RQB/PB17, L1ST4/L1RQA/PB16, BRGO3/PB15, RSTRT1/PB14, L1ST1/RTS1/DREQ0/PC15, L1ST2/RTS2/DREQ1/PC14, L1ST3/L1RQB/PC13, L1ST4/L1RQA/PC12, CTS1/PC11, TGATE1/CD1/PC10, CTS2/PC9, TGATE2/CD2/PC8, CTS3/SDACK2/L1TSYNCB/PC7, CD3/L1RSYNCB/PC6, CTS4/SDACK1/L1TSYNCA/PC5, CD4/L1RSYNCA/PC4, PD15/L1TSYNCA, PD14/L1RSYNCA, PD13/L1TSYNCB, PD12/L1RSYNCB, PD11/RXD3, PD10/TXD3, PD9/RXD4, PD8/TXD4, PD5/REJECT2, PD6/RTS4, PD7/RTS3, PD4/REJECT3, PD3, MII_MDC, MII_TX_ER, MII_EN, MII_MDIO, MII_TXD[0:3].

5 BDIP/GPL_B(5), BR, BG, FRZ/IRQ6, CS(0:5), CS(6)/CE(1)_B, CS(7)/CE(2)_B, WE0/BS_B0/IORD, WE1/BS_B1/IOWR, WE2/BS_B2/PCOE, WE3/BS_B3/PCWE, BS_A(0:3), GPL_A0/GPL_B0, OE/GPL_A1/GPL_B1, GPL_A(2:3)/GPL_B(2:3)/CS(2:3), UPWAITA/GPL_A4, UPWAITB/GPL_B4, GPL_A5, ALE_A, CE1_A, CE2_A, ALE_B/DSCK/AT1, OP(0:1), OP2/MODCK1/STS, OP3/MODCK2/DSDO, BADDR(28:30).

Table 9. Bus Operation Timings (continued)

Num	Characteristic	33 MHz		40 MHz		50 MHz		66 MHz		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	
B1d	CLKOUT phase jitter peak-to-peak for OSCLK ≥ 15 MHz	—	4	—	4	—	4	—	4	ns
	CLKOUT phase jitter peak-to-peak for OSCLK < 15 MHz	—	5	—	5	—	5	—	5	ns
B2	CLKOUT pulse width low (MIN = 0.4 x B1, MAX = 0.6 x B1)	12.1	18.2	10.0	15.0	8.0	12.0	6.1	9.1	ns
B3	CLKOUT pulse width high (MIN = 0.4 x B1, MAX = 0.6 x B1)	12.1	18.2	10.0	15.0	8.0	12.0	6.1	9.1	ns
B4	CLKOUT rise time	—	4.00	—	4.00	—	4.00	—	4.00	ns
B5	CLKOUT fall time	—	4.00	—	4.00	—	4.00	—	4.00	ns
B7	CLKOUT to A(0:31), BADDR(28:30), RD/$\overline{WR}$, $\overline{BURST}$, D(0:31), DP(0:3) output hold (MIN = 0.25 x B1)	7.60	—	6.30	—	5.00	—	3.80	—	ns
B7a	CLKOUT to TSIZ(0:1), $\overline{REG}$, $\overline{RSV}$, AT(0:3), $\overline{BDIP}$, PTR output hold (MIN = 0.25 x B1)	7.60	—	6.30	—	5.00	—	3.80	—	ns
B7b	CLKOUT to $\overline{BR}$, $\overline{BG}$, FRZ, VFLS(0:1), VF(0:2), IWP(0:2), LWP(0:1), $\overline{STS}$ output hold (MIN = 0.25 x B1)	7.60	—	6.30	—	5.00	—	3.80	—	ns
B8	CLKOUT to A(0:31), BADDR(28:30) RD/$\overline{WR}$, $\overline{BURST}$, D(0:31), DP(0:3), valid (MAX = 0.25 x B1 + 6.3)	—	13.80	—	12.50	—	11.30	—	10.00	ns
B8a	CLKOUT to TSIZ(0:1), $\overline{REG}$, $\overline{RSV}$, AT(0:3), $\overline{BDIP}$, PTR valid (MAX = 0.25 x B1 + 6.3)	—	13.80	—	12.50	—	11.30	—	10.00	ns
B8b	CLKOUT to $\overline{BR}$, $\overline{BG}$, VFLS(0:1), VF(0:2), IWP(0:2), FRZ, LWP(0:1), $\overline{STS}$ valid [4] (MAX = 0.25 x B1 + 6.3)	—	13.80	—	12.50	—	11.30	—	10.00	ns
B9	CLKOUT to A(0:31), BADDR(28:30), RD/$\overline{WR}$, $\overline{BURST}$, D(0:31), DP(0:3), TSIZ(0:1), $\overline{REG}$, $\overline{RSV}$, AT(0:3), PTR High-Z (MAX = 0.25 x B1 + 6.3)	7.60	13.80	6.30	12.50	5.00	11.30	3.80	10.00	ns
B11	CLKOUT to $\overline{TS}$, $\overline{BB}$ assertion (MAX = 0.25 x B1 + 6.0)	7.60	13.60	6.30	12.30	5.00	11.00	3.80	9.80	ns
B11a	CLKOUT to $\overline{TA}$, $\overline{BI}$ assertion (when driven by the memory controller or PCMCIA interface) (MAX = 0.00 x B1 + 9.30 [1])	2.50	9.30	2.50	9.30	2.50	9.30	2.50	9.80	ns
B12	CLKOUT to $\overline{TS}$, $\overline{BB}$ negation (MAX = 0.25 x B1 + 4.8)	7.60	12.30	6.30	11.00	5.00	9.80	3.80	8.50	ns

Table 9. Bus Operation Timings (continued)

Num	Characteristic	33 MHz		40 MHz		50 MHz		66 MHz		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	
B35	A(0:31), BADDR(28:30) to $\overline{CS}$ valid, as requested by control bit BST4 in the corresponding word in the UPM (MIN = 0.25 x B1 – 2.00)	5.60	—	4.30	—	3.00	—	1.80	—	ns
B35a	A(0:31), BADDR(28:30), and D(0:31) to $\overline{BS}$ valid, as Requested by BST1 in the corresponding word in the UPM (MIN = 0.50 x B1 – 2.00)	13.20	—	10.50	—	8.00	—	5.60	—	ns
B35b	A(0:31), BADDR(28:30), and D(0:31) to $\overline{BS}$ valid, as requested by control bit BST2 in the corresponding word in the UPM (MIN = 0.75 x B1 – 2.00)	20.70	—	16.70	—	13.00	—	9.40	—	ns
B36	A(0:31), BADDR(28:30), and D(0:31) to $\overline{GPL}$ valid as requested by control bit GxT4 in the corresponding word in the UPM (MIN = 0.25 x B1 – 2.00)	5.60	—	4.30	—	3.00	—	1.80	—	ns
B37	UPWAIT valid to CLKOUT falling edge [8] (MIN = 0.00 x B1 + 6.00)	6.00	—	6.00	—	6.00	—	6.00	—	ns
B38	CLKOUT falling edge to UPWAIT valid[8] (MIN = 0.00 x B1 + 1.00)	1.00	—	1.00	—	1.00	—	1.00	—	ns
B39	$\overline{AS}$ valid to CLKOUT rising edge [9] (MIN = 0.00 x B1 + 7.00)	7.00	—	7.00	—	7.00	—	7.00	—	ns
B40	A(0:31), TSIZ(0:1), RD/$\overline{WR}$, $\overline{BURST}$, valid to CLKOUT rising edge (MIN = 0.00 x B1 + 7.00)	7.00	—	7.00	—	7.00	—	7.00	—	ns
B41	$\overline{TS}$ valid to CLKOUT rising edge (setup time) (MIN = 0.00 x B1 + 7.00)	7.00	—	7.00	—	7.00	—	7.00	—	ns
B42	CLKOUT rising edge to $\overline{TS}$ valid (hold time) (MIN = 0.00 x B1 + 2.00)	2.00	—	2.00	—	2.00	—	2.00	—	ns
B43	$\overline{AS}$ negation to memory controller signals negation (MAX = TBD)	—	TBD	—	TBD	—	TBD	—	TBD	ns

1 For part speeds above 50 MHz, use 9.80 ns for B11a.

2 The timing required for $\overline{BR}$ input is relevant when the MPC866/859 is selected to work with the internal bus arbiter. The timing for $\overline{BG}$ input is relevant when the MPC866/859 is selected to work with the external bus arbiter.

3 For part speeds above 50 MHz, use 2 ns for B17.

4 The D(0:31) and DP(0:3) input timings B18 and B19 refer to the rising edge of CLKOUT, in which the $\overline{TA}$ input signal is asserted.

5 For part speeds above 50 MHz, use 2 ns for B19.

6 The D(0:31) and DP(0:3) input timings B20 and B21 refer to the falling edge of CLKOUT. This timing is valid only for read accesses controlled by chip-selects under control of the UPM in the memory controller, for data beats, where DLT3 = 1 in the UPM RAM words. (This is only the case where data is latched on the falling edge of CLKOUT.)

7 The timing B30 refers to $\overline{CS}$ when ACS = 00 and to $\overline{WE}$(0:3) when CSNT = 0.

Figure 19 shows the timing for the external bus controlled by the UPM.

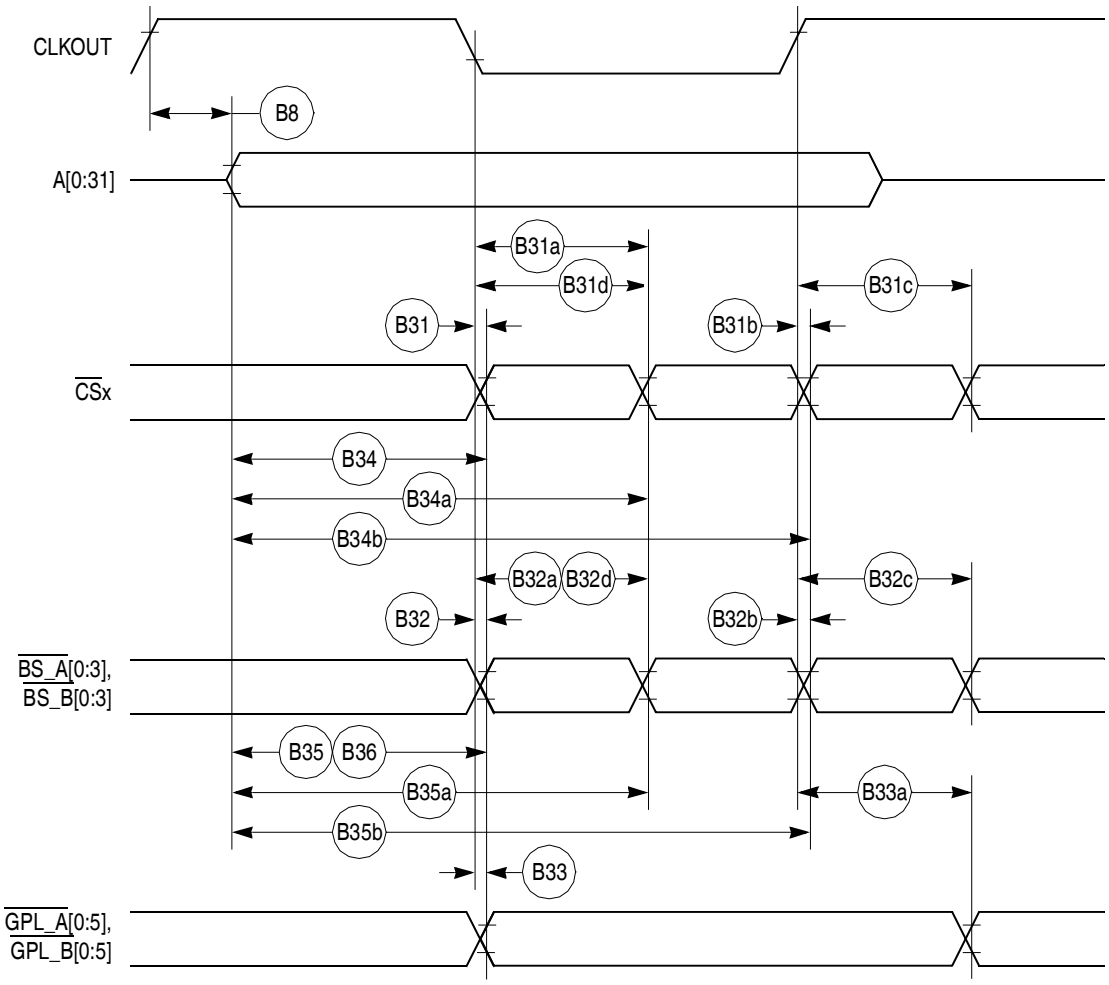

Figure 19. External Bus Timing (UPM Controlled Signals)

Figure 23 shows the timing for the asynchronous external master memory access controlled by the GPCM.

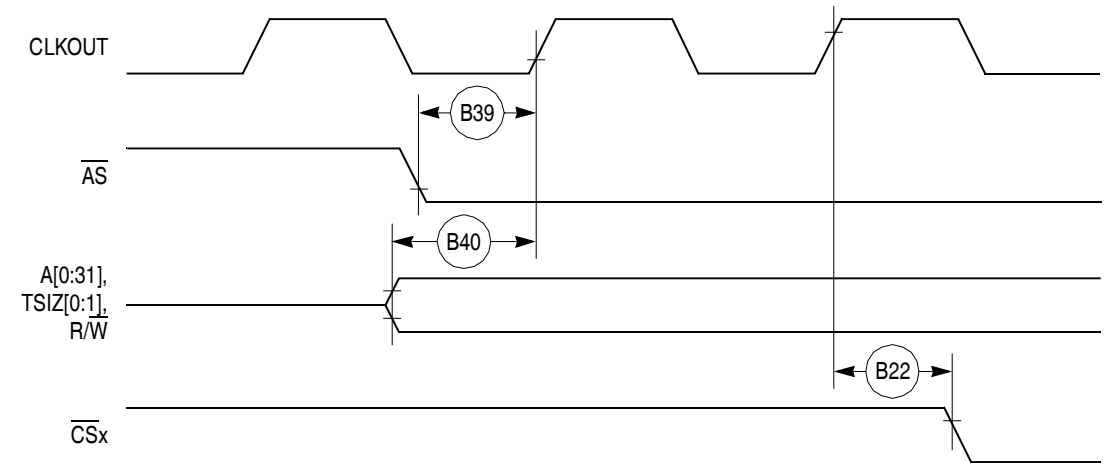

Figure 23. Asynchronous External Master Memory Access Timing (GPCM Controlled—ACS = 00)

Figure 24 shows the timing for the asynchronous external master control signals negation.

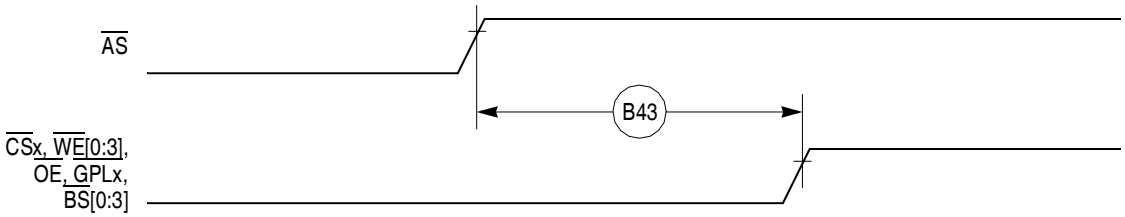

Figure 24. Asynchronous External Master—Control Signals Negation Timing

Table 10 shows the interrupt timing for the MPC866/859.

Table 10. Interrupt Timing

Num	Characteristic [1]	All Frequencies		Unit
		Min	Max	
I39	$\overline{IRQ}$x valid to CLKOUT rising edge (setup time)	6.00	—	ns
I40	$\overline{IRQ}$x hold time after CLKOUT	2.00	—	ns
I41	$\overline{IRQ}$x pulse width low	3.00	—	ns
I42	$\overline{IRQ}$x pulse width high	3.00	—	ns
I43	$\overline{IRQ}$x edge-to-edge time	$4xT_{CLOCKOUT}$	—	—

[1] The timings I39 and I40 describe the testing conditions under which the $\overline{IRQ}$ lines are tested when being defined as level sensitive. The $\overline{IRQ}$ lines are synchronized internally and do not have to be asserted or negated with reference to the CLKOUT.
The timings I41, I42, and I43 are specified to allow the correct function of the $\overline{IRQ}$ lines detection circuitry, and has no direct relation with the total system interrupt latency that the MPC866/859 is able to support.

Table 13 shows the debug port timing for the MPC866/859.

Table 13. Debug Port Timing

Num	Characteristic	All Frequencies		Unit
		Min	Max	
D61	DSCK cycle time	$3xT_{CLOCKOUT}$	—	
D62	DSCK clock pulse width	$1.25xT_{CLOCKOUT}$	—	
D63	DSCK rise and fall times	0.00	3.00	ns
D64	DSDI input data setup time	8.00	—	ns
D65	DSDI data hold time	5.00	—	ns
D66	DSCK low to DSDO data valid	0.00	15.00	ns
D67	DSCK low to DSDO invalid	0.00	2.00	ns

Figure 32 shows the input timing for the debug port clock.

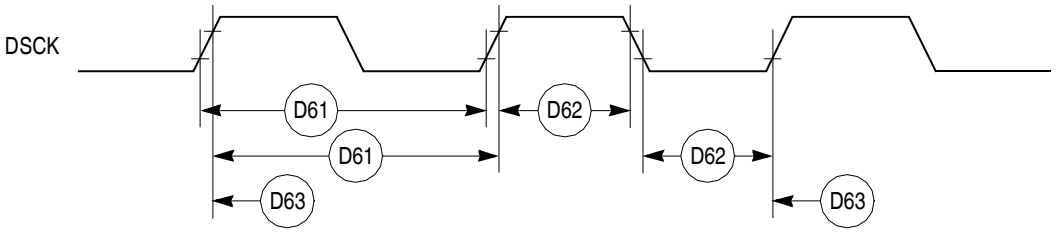

Figure 32. Debug Port Clock Input Timing

Figure 33 shows the timing for the debug port.

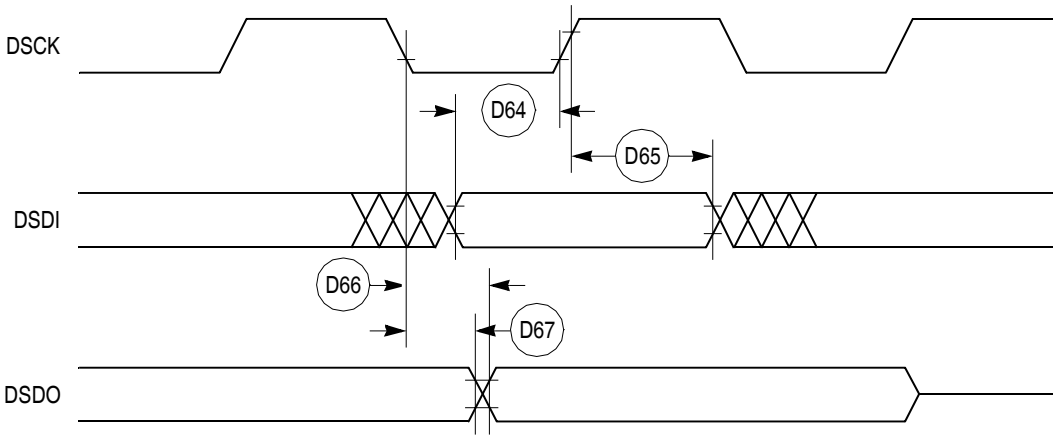

Figure 33. Debug Port Timings

Table 14 shows the reset timing for the MPC866/859.

Table 14. Reset Timing

Num	Characteristic	33 MHz		40 MHz		50 MHz		66 MHz		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	
R69	CLKOUT to $\overline{\text{HRESET}}$ high impedance (MAX = 0.00 x B1 + 20.00)	—	20.00	—	20.00	—	20.00	—	20.00	ns
R70	CLKOUT to $\overline{\text{SRESET}}$ high impedance (MAX = 0.00 x B1 + 20.00)	—	20.00	—	20.00	—	20.00	—	20.00	ns
R71	$\overline{\text{RSTCONF}}$ pulse width (MIN = 17.00 x B1)	515.20	—	425.00	—	340.00	—	257.60	—	ns
R72	—	—	—	—	—	—	—	—	—	—
R73	Configuration data to HRESET rising edge setup time (MIN = 15.00 x B1 + 50.00)	504.50	—	425.00	—	350.00	—	277.30	—	ns
R74	Configuration data to $\overline{\text{RSTCONF}}$ rising edge setup time (MIN = 0.00 x B1 + 350.00)	350.00	—	350.00	—	350.00	—	350.00	—	ns
R75	Configuration data hold time after $\overline{\text{RSTCONF}}$ negation (MIN = 0.00 x B1 + 0.00)	0.00	—	0.00	—	0.00	—	0.00	—	ns
R76	Configuration data hold time after $\overline{\text{HRESET}}$ negation (MIN = 0.00 x B1 + 0.00)	0.00	—	0.00	—	0.00	—	0.00	—	ns
R77	$\overline{\text{HRESET}}$ and $\overline{\text{RSTCONF}}$ asserted to data out drive (MAX = 0.00 x B1 + 25.00)	—	25.00	—	25.00	—	25.00	—	25.00	ns
R78	$\overline{\text{RSTCONF}}$ negated to data out high impedance (MAX = 0.00 x B1 + 25.00)	—	25.00	—	25.00	—	25.00	—	25.00	ns
R79	CLKOUT of last rising edge before chip three-states $\overline{\text{HRESET}}$ to data out high impedance (MAX = 0.00 x B1 + 25.00)	—	25.00	—	25.00	—	25.00	—	25.00	ns
R80	DSDI, DSCK setup (MIN = 3.00 x B1)	90.90	—	75.00	—	60.00	—	45.50	—	ns
R81	DSDI, DSCK hold time (MIN = 0.00 x B1 + 0.00)	0.00	—	0.00	—	0.00	—	0.00	—	ns
R82	$\overline{\text{SRESET}}$ negated to CLKOUT rising edge for DSDI and DSCK sample (MIN = 8.00 x B1)	242.40	—	200.00	—	160.00	—	121.20	—	ns

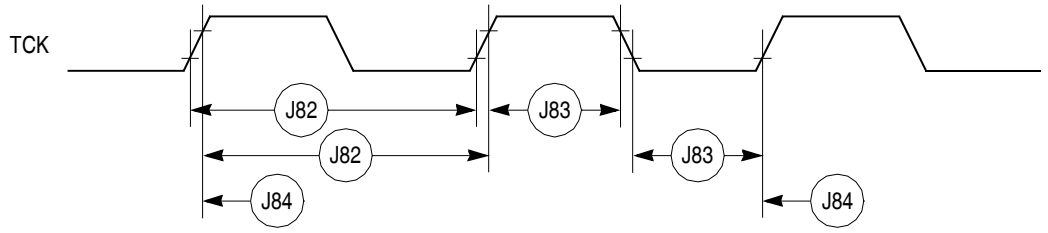

Figure 37. JTAG Test Clock Input Timing

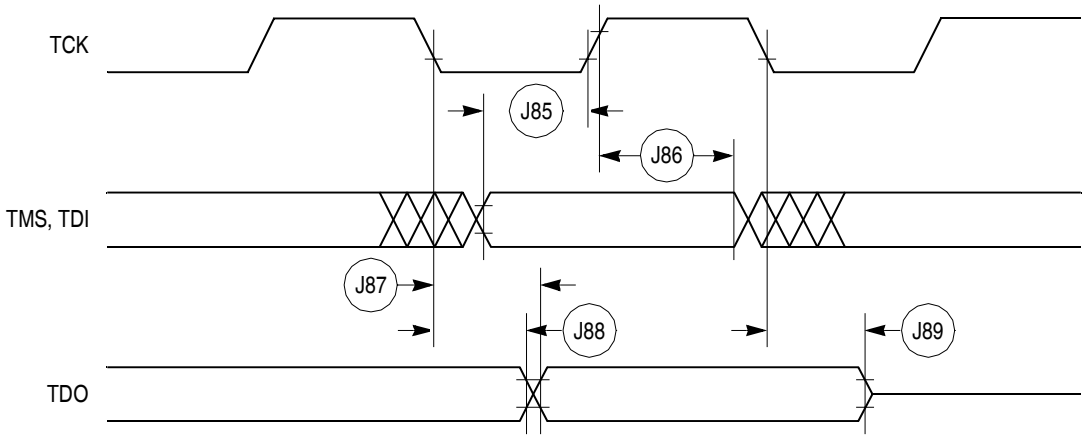

Figure 38. JTAG Test Access Port Timing Diagram

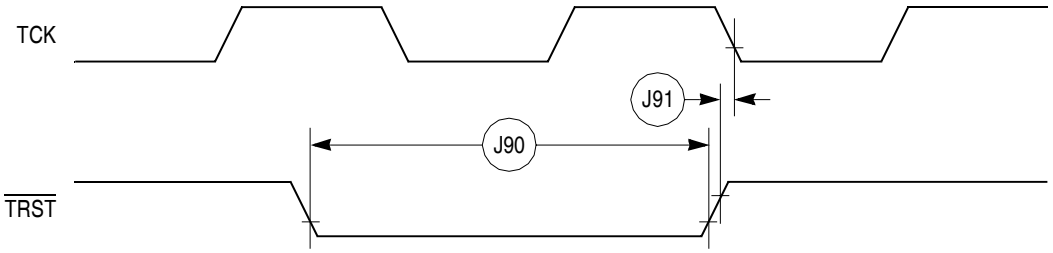

Figure 39. JTAG $\overline{\text{TRST}}$ Timing Diagram

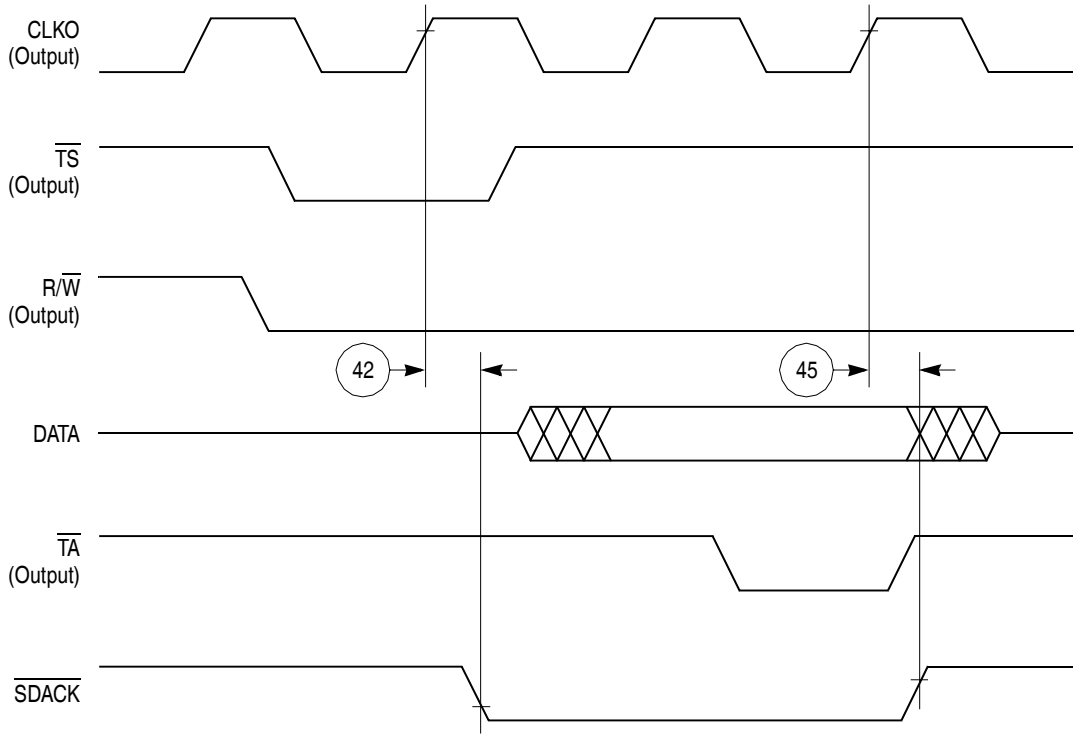

Figure 50. SDACK Timing Diagram—Peripheral Read, Internally-Generated TA

12.4 Baud Rate Generator AC Electrical Specifications

Table 19 shows the baud rate generator timings as shown in Figure 51.

Table 19. Baud Rate Generator Timing

Num	Characteristic	All Frequencies		Unit
		Min	Max	
50	BRGO rise and fall time	—	10	ns
51	BRGO duty cycle	40	60	%
52	BRGO cycle	40	—	ns

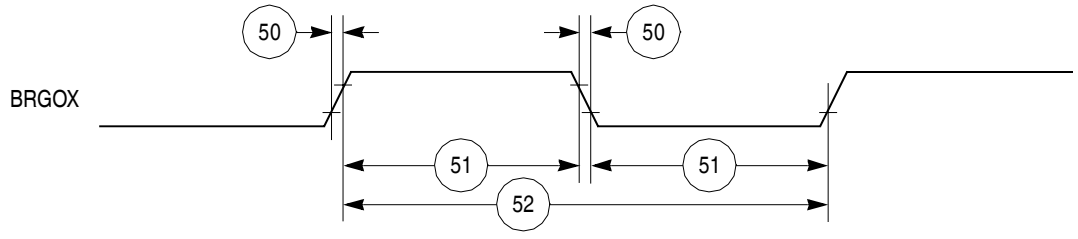

Figure 51. Baud Rate Generator Timing Diagram

Table 21. SI Timing (continued)

Num	Characteristic	All Frequencies		Unit
		Min	Max	
74	L1CLK edge to L1RSYNC, L1TSYNC, invalid (SYNC hold time)	35.00	—	ns
75	L1RSYNC, L1TSYNC rise/fall time	—	15.00	ns
76	L1RXD valid to L1CLK edge (L1RXD setup time)	17.00	—	ns
77	L1CLK edge to L1RXD invalid (L1RXD hold time)	13.00	—	ns
78	L1CLK edge to L1ST(1–4) valid [4]	10.00	45.00	ns
78A	L1SYNC valid to L1ST(1–4) valid	10.00	45.00	ns
79	L1CLK edge to L1ST(1–4) invalid	10.00	45.00	ns
80	L1CLK edge to L1TXD valid	10.00	55.00	ns
80A	L1TSYNC valid to L1TXD valid [4]	10.00	55.00	ns
81	L1CLK edge to L1TXD high impedance	0.00	42.00	ns
82	L1RCLK, L1TCLK frequency (DSC =1)	—	16.00 or SYNCCLK/2	MHz
83	L1RCLK, L1TCLK width low (DSC =1)	P + 10	—	ns
83a	L1RCLK, L1TCLK width high (DSC = 1)[3]	P + 10	—	ns
84	L1CLK edge to L1CLKO valid (DSC = 1)	—	30.00	ns
85	$\overline{\text{L1RQ}}$ valid before falling edge of L1TSYNC[4]	1.00	—	L1TCLK
86	L1GR setup time[2]	42.00	—	ns
87	L1GR hold time	42.00	—	ns
88	L1CLK edge to L1SYNC valid (FSD = 00) CNT = 0000, BYT = 0, DSC = 0)	—	0.00	ns

1 The ratio SyncCLK/L1RCLK must be greater than 2.5/1.

2 These specs are valid for IDL mode only.

3 Where P = 1/CLKOUT. Thus, for a 25-MHz CLKO1 rate, P = 40 ns.

4 These strobes and TxD on the first bit of the frame become valid after L1CLK edge or L1SYNC, whichever is later.

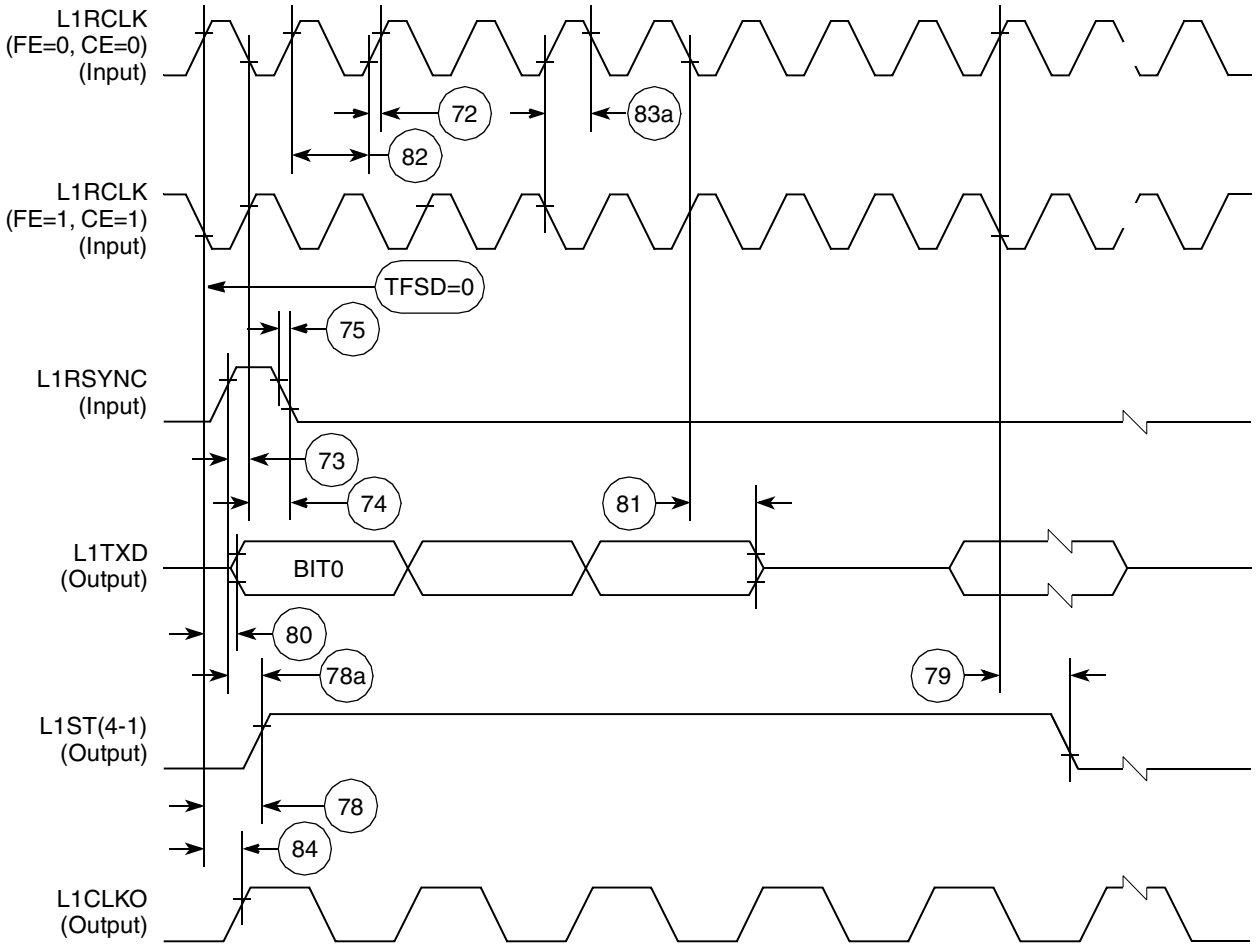

Figure 56. SI Transmit Timing with Double Speed Clocking (DSC = 1)

Figure 58 through Figure 60 show the NMSI timings.

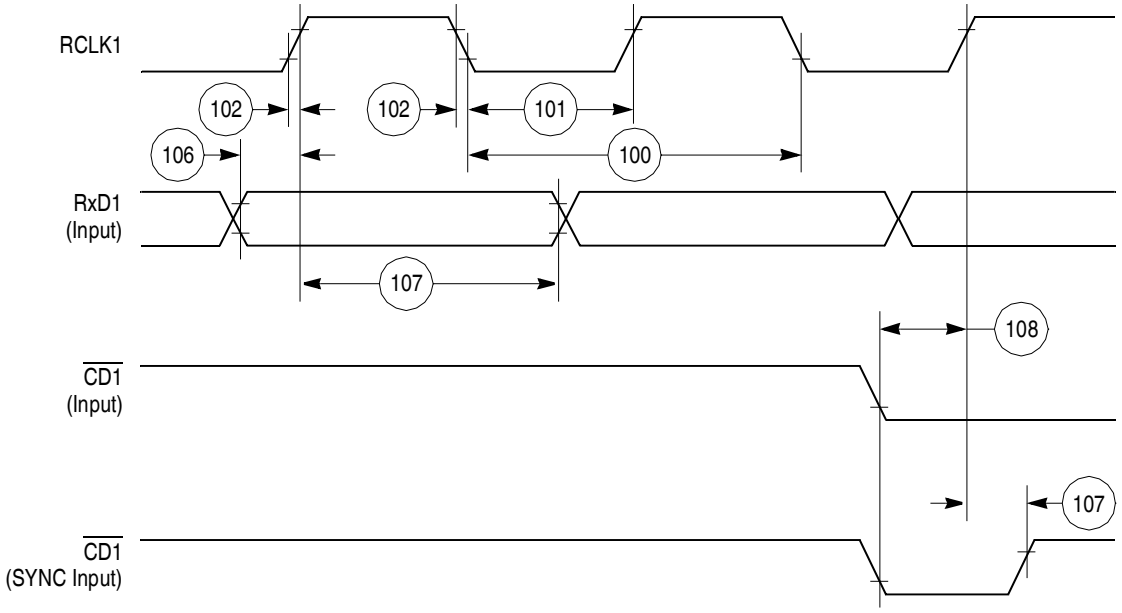

Figure 58. SCC NMSI Receive Timing Diagram

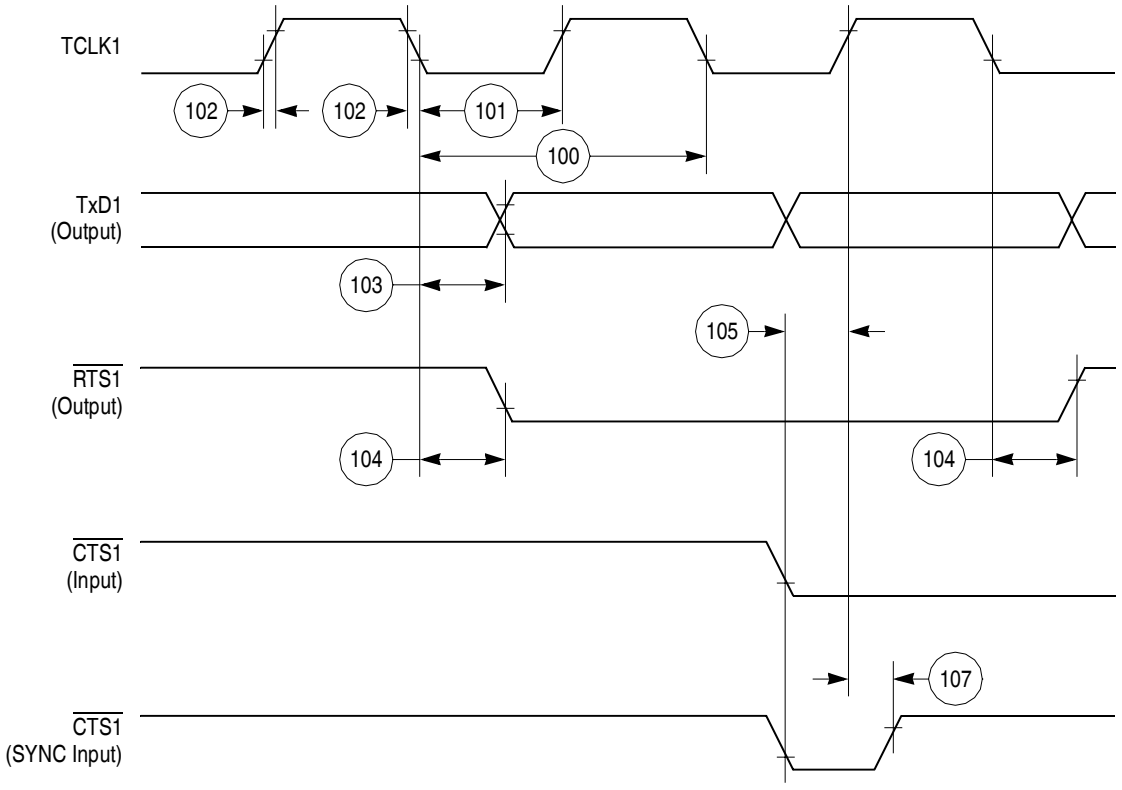

Figure 59. SCC NMSI Transmit Timing Diagram

Table 32. UTOPIA Slave (Split Bus Mode) Electrical Specifications

Num	Signal Characteristic	Direction	Min	Max	Unit
U1	UtpClk rise/fall time (external clock option)	Input	—	4	ns
	Duty cycle		40	60	%
	Frequency		—	33	MHz
U2	UTPB, SOC, Rxclav and Txclav active delay	Output	2	16	ns
U3	UTPB_AUX, SOC_Aux, $\overline{\text{RxEnb}}$, $\overline{\text{TxEnb}}$, RxAddr, and TxAddr setup time	Input	4	—	ns
U4	UTPB_AUX, SOC_Aux, $\overline{\text{RxEnb}}$, $\overline{\text{TxEnb}}$, RxAddr, and TxAddr hold time	Input	1	—	ns

Figure 72 shows signal timings during UTOPIA receive operations.

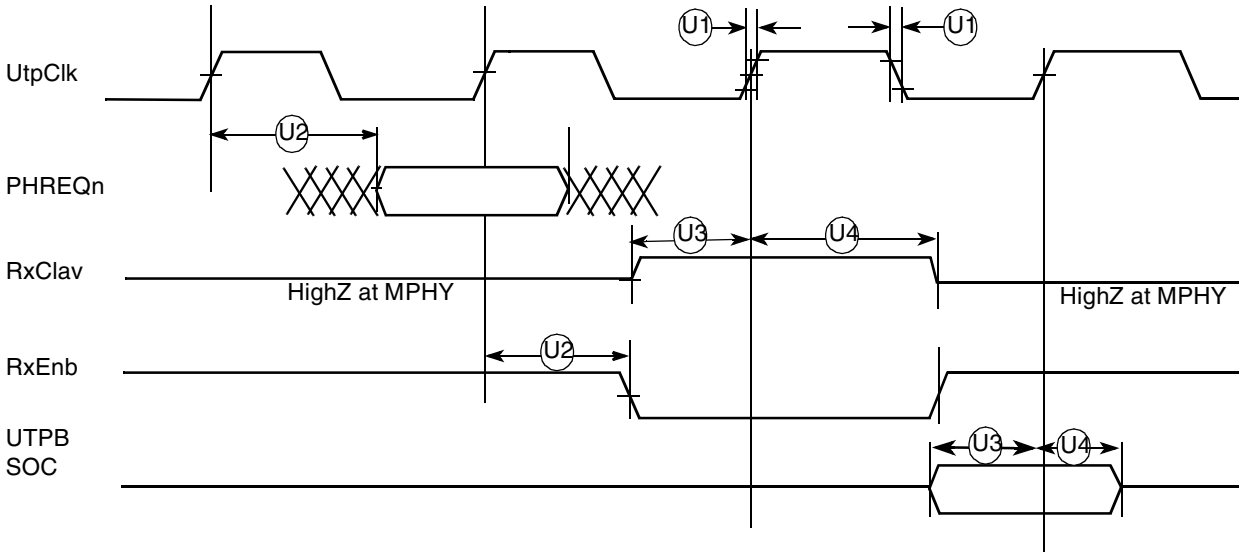

Figure 72. UTOPIA Receive Timing

15.1 Pin Assignments

Figure 78 shows the top view pinout of the PBGA package. For additional information, see the *MPC866 PowerQUICC Family User's Manual*.

NOTE: This is the top view of the device.

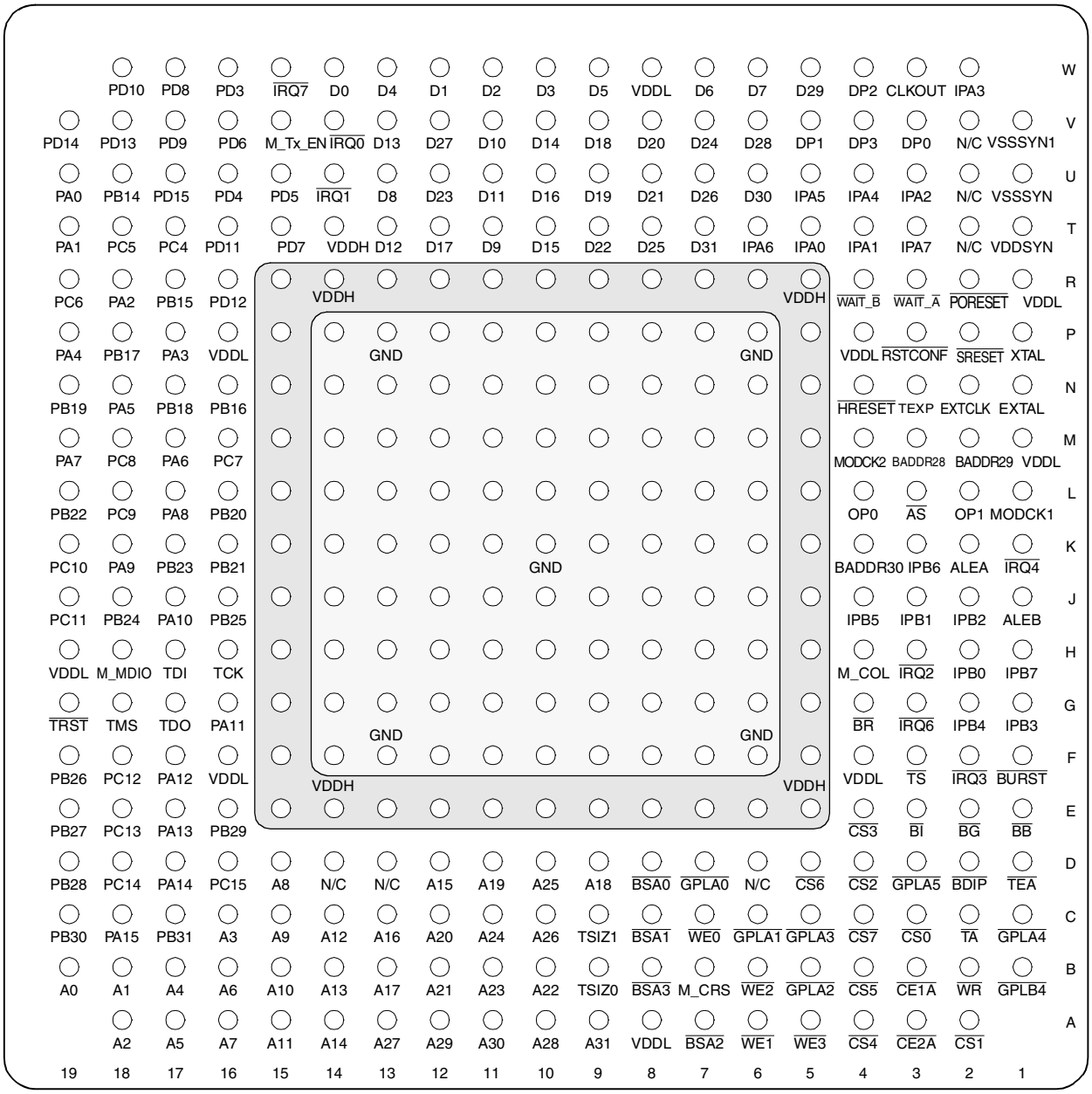

Figure 78. Pinout of the PBGA Package

Table 39. Pin Assignments (continued)

Name	Pin Number	Type
OP3 MODCK2 DSDO	M4	Bidirectional
BADDR30 $\overline{\text{REG}}$	K4	Output
BADDR[28:29]	M3, M2	Output
$\overline{\text{AS}}$	L3	Input
PA15 RXD1 RXD4	C18	Bidirectional
PA14 TXD1 TXD4	D17	Bidirectional (Optional: Open-drain)
PA13 RXD2	E17	Bidirectional
PA12 TXD2	F17	Bidirectional (Optional: Open-drain)
PA11 L1TXDB RXD3	G16	Bidirectional (Optional: Open-drain)
PA10 L1RXDB TXD3	J17	Bidirectional (Optional: Open-drain)
PA9 L1TXDA RXD4	K18	Bidirectional (Optional: Open-drain)
PA8 L1RXDA TXD4	L17	Bidirectional (Optional: Open-drain)
PA7 CLK1 L1RCLKA BRGO1 TIN1	M19	Bidirectional
PA6 CLK2 $\overline{\text{TOUT1}}$	M17	Bidirectional

Table 39. Pin Assignments (continued)

Name	Pin Number	Type
MII_COL	H4	Input
VSSSYN1	V1	PLL analog VDD and GND
VSSSYN	U1	Power
VDDSYN	T1	Power
GND	F6, F7, F8, F9, F10, F11, F12, F13, F14, G6, G7, G8, G9, G10, G11, G12, G13, G14, H6, H7, H8, H9, H10, H11, H12, H13, H14, J6, J7, J8, J9, J10, J11, J12, J13, J14, K6, K7, K8, K9, K10, K11, K12, K13, K14, L6, L7, L8, L9, L10, L11, L12, L13, L14, M6, M7, M8, M9, M10, M11, M12, M13, M14, N6, N7, N8, N9, N10, N11, N12, N13, N14, P6, P7, P8, P9, P10, P11, P12, P13, P14	Power
VDDL	A8, M1, W8, H19, F4, F16, P4, P16, R1	Power
VDDH	E5, E6, E7, E8, E9, E10, E11, E12, E13, E14, E15, F5, F15, G5, G15, H5, H15, J5, J15, K5, K15, L5, L15, M5, M15, N5, N15, P5, P15, R5, R6, R7, R8, R9, R10, R11, R12, R13, R14, R15, T14	Power
N/C	D6, D13, D14, U2, V2, T2	No-connect

1 Classic SAR mode only

2 ESAR mode only

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